Discrete POWER & Signal **Technologies**

TIS93

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FAIRCHILD

SEMICONDUCTOR TM



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	40	V	
V _{CBO}	Collector-Base Voltage	40	V	
V _{EBO}	Emitter-Base Voltage 5.0		V	
I _C	Collector Current - Continuous 800		mA	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	5 to +150 °C	

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Thermal Characteristics TA = 25°C unless otherwise noted				
Symbol	Characteristic	Max	Units	
		TIS93		
P _D	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W	

PNP General Purpose Amplifier (continued)

Symbol	Parameter Test Conditions		Min	Мах	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 100 \ \mu {\rm A}, \ I_{\rm C} = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, \text{ I}_{E} = 0$		100	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_C = 0$		100	nA
	•		-		-
ON CHAF	RACTERISTICS*				
h _{FE}	DC Current Gain	$V_{CE} = 2.0 \text{ V}, I_{C} = 50 \text{ mA}$	100	300	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50$ mA, $I_{\rm B} = 5.0$ mA		0.25	V
V _{BE(on)}	Base-Emitter On Voltage	$V_{CE} = 2.0 \text{ V}, I_{C} = 50 \text{ mA}$	0.6	1.0	V

*Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

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PRODUCT STATUS DEFINITIONS

Definition of Terms

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